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Topological interface states have been demonstrated for a wide range of excitations (photons, phonons, vibrations, polaritons). In particular, nanoacoustic interface states have been evidenced in superlattices working at acoustic frequencies in the tens to hundreds of GHz [1–3]. A scheme to generate interface states in one-dimensional nanoacoustic superlattices is based on the principle of band inversion, which can be achieved by concatenating two periodic lattices with inverted spatial mode symmetries around the bandgap [4]. Most realizations optimize the thickness ratio to reverse the symmetries to create an interface mode at a specific bandgap.

In this work, we present topological nanophononic interface states at high-order bandgaps in multilayered structures based on GaAs/AlAs. We achieve band inversion by modifying the internal unit cell structure of the two lattices [5]. We extend the principle of band inversion to create an interface state at the second or higher-order bandgaps (see Fig.1). By carefully choosing the appropriate material thickness ratio of the two concatenated nanoacoustic superlattices we demonstrate that we can engineer interface states at the n<sup>th</sup> bandgap. We can design versatile topological devices where nanoacoustic interface states are simultaneously created in a broad frequency range. In addition, we can generate interface states in hybrid structures by combining two superlattices presenting bandgaps of different orders centered around the same frequency.

## References

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- [3] G. Arregui et al., APL Photonics 4, 030805 (2019)
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- [5] M. Esmann et al., Phys. Rev. B 97, 155422 (2018)

Figures



**Figure 1:** Band inversion of the acoustic bandgap. The mode symmetries are indicated with orange (symmetric) and blue (anti-symmetric) lines.